

ECE SET-C

2013

2013

Question Booklet Code -



EC: ELECTRONICS AND COMMUNICATION ENGINEERING

Duration: Three Hours

Maximum Marks: 100

Read the following instructions carefully.

- Do not open the seal of the Question Booklet until you are asked to do so by the invigilator.
- Take out the Optical Response Sheet (ORS) from this Question Booklet without breaking the seal and read the instructions printed on the ORS carefully. If you find that either:
 - a. The Question Booklet Code printed at the right hand top corner of this page does not match with the Question Booklet Code at the right hand top corner of the ORS or
 - b. The Question Paper Code preceding the Registration number on the ORS is not EC, then exchange the booklet immediately with a new sealed Question Booklet.
- 3. On the right hand side of the ORS, using ONLY a black ink ballpoint pen, (i) darken the appropriate bubble under each digit of your registration number and (ii) write your registration number, your name and name of the examination centre and put your signature at the specified location.
- This Question Booklet contains 24 pages including blank pages for rough work. After you are
 permitted to open the seal, check all pages and report discrepancies, if any, to the invigilator.
- 5. There are a total of 65 questions carrying 100 marks. All these questions are of objective type. Each question has only one correct answer. Questions must be answered on the left hand side of the ORS by darkening the appropriate bubble (marked A, B, C, D) using ONLY a black ink ballpoint pen against the question number. For each question darken the bubble of the correct answer. More than one answer bubbled against a question will be treated as an incorrect response.
- Since bubbles darkened by the black ink ballpoint pen cannot be erased, candidates should darken the bubbles in the ORS very carefully.
- 7. Questions Q.1 Q.25 carry 1 mark each. Questions Q.26 Q.55 carry 2 marks each. The 2 marks questions include two pairs of common data questions and two pairs of linked answer questions. The answer to the second question of the linked answer questions depends on the answer to the first question of the pair. If the first question in the linked pair is wrongly answered or is not attempted, then the answer to the second question in the pair will not be evaluated.
- Questions Q.56 Q.65 belong to General Aptitude (GA) section and carry a total of 15 marks.
 Questions Q.56 Q.60 carry 1 mark each, and questions Q.61 Q.65 carry 2 marks each.
- 9. Questions not attempted will result in zero mark and wrong answers will result in NEGATIVE marks. For all 1 mark questions, ½ mark will be deducted for each wrong answer. For all 2 marks questions, ¾ mark will be deducted for each wrong answer. However, in the case of the linked answer question pair, there will be negative marks only for wrong answer to the first question and no negative marks for wrong answer to the second question.
- 10. Calculator is allowed whereas charts, graph sheets or tables are NOT allowed in the examination hall.
- Rough work can be done on the Question Booklet itself. Blank pages are provided at the end of the Question Booklet for rough work.
- Before the start of the examination, write your name and registration number in the space provided below using a black ink ballpoint pen.

Registration Number	EC	,			120	



ECE SET-C

ELECTRONICS & COMMN. ENGG. - EC 2013 Q.1 to Q.25 carry one mark each. The bit rate of a digital communication system is R kbits/s. The modulation used is 32-QAM. The Q.1 minimum bandwidth required for ISI free transmission is (B) R/10 kHz (D) R/5 kHz R/5 Hz (A) R/10 Hz For 8085 microprocessor, the following program is executed. Q.2 MVI A, 05H; MVI B; 05H; PTR: ADD B; DCR B) JNZ PTR; ADI 03H; At the end of program, accumulator contains (D) 05H (B) 20H (C) 23H (A) 17H Consider a delta connection of resistors and its equivalent star connection as shown below. If all Q.3 elements of the delta connection are scaled by a factor k, k> 0, the elements of the corresponding star equivalent will be scaled by a factor of (D) √k $(A) k^2$ (C) 1/k In the circuit shown below what is the output voltage (Vout) if a silicon transistor Q and an ideal Q.4 op-amp are used? -> +15 $1 k\Omega$

EC-C

(A) -15 V

2013

2/24

(C) +0.7 V

(D) +15 V



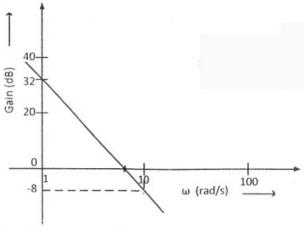
ECE SET-C

2013

2013

ELECTRONICS & COMMN. ENGG. - EC

The Bode plot of a transfer function G(s) is shown in the figure below. Q.5



The gain $(20 \log |G(s)|)$ is 32 dB and -8 dB at 1 rad/s and 10 rad/s respectively. The phase is negative for all ω . Then G(s) is

(A)
$$\frac{39.8}{s}$$

$$\sqrt{8}$$
) $\frac{39.8}{s^2}$

(C)
$$\frac{32}{s}$$

(C)
$$\frac{32}{s}$$
 (D) $\frac{32}{s^2}$

Q.6 The impulse response of a system is h(t) = t u(t). For an input u(t-1), the output is

(A)
$$\frac{t^2}{2}u(t)$$

(B)
$$\frac{t(t-1)}{2}u(t-1)$$

(B)
$$\frac{t(t-1)}{2}u(t-1)$$
 (D) $\frac{t^2-1}{2}u(t-1)$

(D)
$$\frac{t^2-1}{2}u(t-1)$$

The divergence of the vector field $\vec{A} = x\hat{a}_x + y\hat{a}_y + z\hat{a}_z$ is Q.7





(D) 3

The maximum value of θ until which the approximation $\sin \theta \approx \theta$ holds to within 10% error is

(A) 10°

(A) 0

- (B) 18°
- (C) 50°
- (D) 90°

Q.9 In IC technology, dry oxidation (using dry oxygen) as compared to wet oxidation (using steam or water vapor) produces

- (A) superior quality oxide with a higher growth rate
- (B) inferior quality oxide with a higher growth rate
- (C) inferior quality oxide with a lower growth rate
- (D) superior quality oxide with a lower growth rate

Q.10 In a forward biased pn junction diode, the sequence of events that best describes the mechanism of current flow is

- (A) injection, and subsequent diffusion and recombination of minority carriers
- (B) injection, and subsequent drift and generation of minority carriers
- (C) extraction, and subsequent diffusion and generation of minority carriers
- (D) extraction, and subsequent drift and recombination of minority carriers

EC-C



ECE SET-C

2013			EL	ECTRONICS & COMMN. ENGG EC	
Q.11		impulse responses $h_1(t)$ f the cascaded system is		ed in cascade. Then the overall	
	(A) product of $h_1(t)$) and $h_2(t)$			
	(B) sum of $h_1(t)$ a				
	(C) convolution of				
	(D) subtraction of				
Q.12	Consider a vector f	field $\vec{A}(\vec{r})$. The closed lo	op line integral $\oint \vec{A} \cdot d\vec{l}$	can be expressed as	
	(A) $\bigoplus (\nabla \times \vec{A}) \bullet \vec{a}$	s over the closed surface	e bounded by the loop		
	(B) $\bigoplus (\nabla \cdot \bar{A})d$	v over the closed volume	e bounded by the loop		
		over the open volume b			
	***	s over the open surface			
Q.13	first floor. The bu	lb can be turned ON an	d also can be turned Ol The logic of switching of		ø
	(A) an AND gate	(B) an OR gate	(C) an XOR gate	(D) a NAND gate	
Q.14	Let $g(t) = e^{-\pi t^2}$, the Fourier transfo			s applied as input to $h(t)$, then	
\	(A) $e^{-\pi f^2}$	(B) $e^{-\pi f^2/2}$	(C) $e^{-\pi f }$	(D) $e^{-2\pi f^2}$	
Q.15		a device is found to be		nding wave ratio (VSWR) and	
,	(A) 1.22 and 0.1	(B) 0.81 and 0.1	(C) -1.22 and 0.1	(D) 2.44 and 0.2	
Q.16				β) Ω If a purely resistive load source, its value in Ω should be	
	(A) 3	(B) 4	(C) 5	(D) 7	
		~			
	598				
- 7					

2013



2013

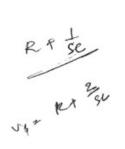
A Team of IES & GATE Toppers

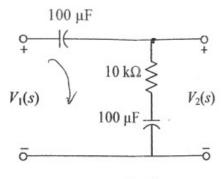
ECE SET-C

2013

ELECTRONICS & COMMN. ENGG. - EC

Q.17 The transfer function $\frac{V_2(s)}{V_1(s)}$ of the circuit shown below is





(A)
$$\frac{0.5s+1}{s+1}$$

(C)
$$\frac{s+2}{s+1}$$

(B)
$$\frac{3s+6}{s+2}$$

$$\sqrt{\frac{s+1}{s+2}}$$

Q.18 Assuming zero initial condition, the response y(t) of the system given below to a unit step input u(t) is



(B) tu(t



(D) $e^{-t} u(t)$

Q.19 A polynomial $f(x) = a_4 x^4 + a_3 x^3 + a_2 x^2 + a_1 x - a_0$ with all coefficients positive has

(A) no real roots

- (B) no negative real root
- (C) odd number of real roots
- (D) at least one positive and one negative real root

Q.20 The minimum eigenvalue of the following matrix is

- (A) 0
- (B) 1
- (C)2
- (D) 3

Q.21 Which one of the following statements is NOT TRUE for a continuous time causal and stable LTI system?

- (A) All the poles of the system must lie on the left side of the $j\omega$ axis.
- (B) Zeros of the system can lie anywhere in the s-plane.
- (C) All the poles must lie within |s| = 1.
- (D) All the roots of the characteristic equation must be located on the left side of the $j\omega$ axis.

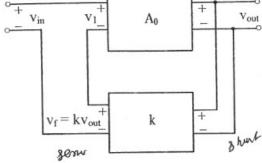
EC-C

(



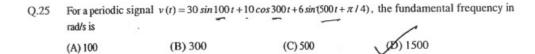
ECE SET-C

			India's Best	Institute for IES, GATE & PSUS	
20	13		A Team of IES	& GATE Toppers	
2013				ELECTRONICS & COMMN.	ENGG EC
Q.22	In a MOSFET op	erating in the saturation	region, the channel leng	th modulation effect caus	ses
Q.23	(B) a decrease in (C) a decrease in (D) a decrease in (D)	in the gate-source capaci in the transconductance in the unity-gain cutoff from the output resistance signal with a maximum in, the sampling frequence	frequency of 5 kHz is	to be sampled. Accordi	ng to the
	(A) 5 kHz	(B) 12 kHz	(C) 15 kHz	(D) 20 kHz	
Q.24	In a voltage-volt		below, which one of th	e following statements is	TRUE if
28		+ V _{in} V ₁	+ A ₀	+ V _{out}	



- (A) The input impedance increases and output impedance decreases.

 (B) The input impedance increases and output impedance also increases.
- (C) The input impedance decreases and output impedance also decreases.
- (D) The input impedance decreases and output impedance increases.





2013

A Team of IES & GATE Toppers

ECE SET-C

2013

ELECTRONICS & COMMN. ENGG. - EC

Q.26 to Q.55 carry two marks each.

Q.26 A system is described by the differential equation $\frac{d^2y}{dt^2} + 5\frac{dy}{dt} + 6y(t) = x(t)$.

Let x(t) be a rectangular pulse given by

$$x(t) = \begin{cases} 1 & 0 < t < 2 \\ 0 & otherwise \end{cases}$$

Assuming that y(0) = 0 and $\frac{dy}{dt} = 0$ at t = 0, the Laplace transform of y(t) is

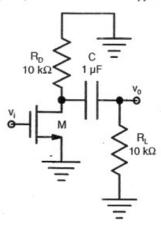
(A)
$$\frac{e^{-2s}}{s(s+2)(s+3)}$$

$$(B) \frac{1-e^{-2s}}{s(s+2)(s+3)}$$

(C)
$$\frac{e^{-2s}}{(s+2)(s+3)}$$

(D)
$$\frac{1-e^{-2s}}{(s+2)(s+3)}$$

Q.27 The ac schematic of an NMOS common-source stage is shown in the figure below, where part of the biasing circuits has been omitted for simplicity. For the n-channel MOSFET M, the transconductance $g_m = 1$ mA/V, and body effect and channel length modulation effect are to be neglected. The lower cutoff frequency in Hz of the circuit is approximately at





(B) 32

(C) 50

(D) 200

EC-C



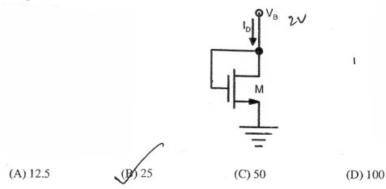
ECE SET-C

2013

2013

ELECTRONICS & COMMN. ENGG. - EC

Q.28 The small-signal resistance (i.e., dV_B/dI_D) in $k\Omega$ offered by the n-channel MOSFET M shown in the figure below, at a bias point of $V_B = 2$ V is (device data for M: device transconductance parameter $k_N = \mu_n C'_{ox} (W/L) = 40 \ \mu \text{A/V}^2$, threshold voltage $V_{TN} = 1$ V, and neglect body effect and channel length modulation effects)



Q.29 The impulse response of a continuous time system is given by $h(t) = \delta(t-1) + \delta(t-3)$. The value of the step response at t = 2 is

(A) 0



(C) 2

(D) 3

Q.30 Two magnetically uncoupled inductive coils have Q factors q_1 and q_2 at the chosen operating frequency. Their respective resistances are R_1 and R_2 . When connected in series, their effective Q factor at the same operating frequency is

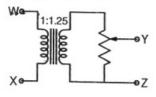
(A)
$$q_1 + q_2$$

(B)
$$(1/q_1)+(1/q_2)$$

(C)
$$(q_1R_1+q_2R_2)/(R_1+R_2)$$

(D)
$$(q_1R_2 + q_2R_1)/(R_1 + R_2)$$

Q.31 The following arrangement consists of an ideal transformer and an attenuator which attenuates by a factor of 0.8. An ac voltage $V_{WX1} = 100$ V is applied across WX to get an open circuit voltage V_{YZ1} across YZ. Next, an ac voltage $V_{YZ2} = 100$ V is applied across YZ to get an open circuit voltage V_{WX2} across WX. Then, V_{YZ1}/V_{WX1} , V_{WX2}/V_{YZ2} are respectively,



- (A) 125/100 and 80/100
- (B) 100/100 and 80/100
- (C) 100/100 and 100/100
- (D) 80/100 and 80/100

EC-C



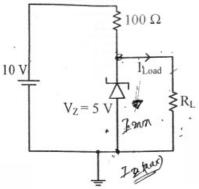
ECE SET-C

2013

2013

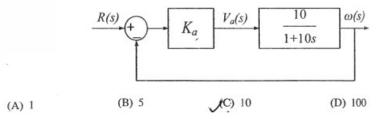
ELECTRONICS & COMMN. ENGG. - EC

Q.32 In the circuit shown below, the knee current of the ideal Zener diode is 10 mA. To maintain 5 V across R_L, the minimum value of R_L in Ω and the minimum power rating of the Zener diode in mW, respectively, are

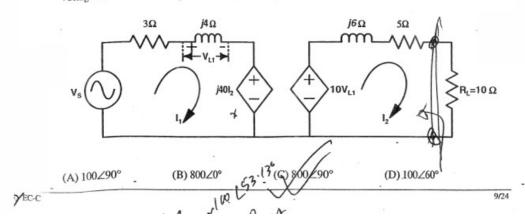


(A) 125 and 125 (B) 125 and 250 (C) 250 and 125 (D) 250 and 250

Q.33 The open-loop transfer function of a dc motor is given as $\frac{\omega(s)}{V_a(s)} = \frac{10}{1+10s}$. When connected in feedback as shown below, the approximate value of K_a that will reduce the time constant of the closed loop system by one hundred times as compared to that of the open-loop system is



Q.34 In the circuit shown below, if the source voltage $V_s = 100 \angle 53.13^{\circ}$ V then the Thevenin's equivalent voltage in Volts as seen by the load resistance R_L is





2013

A Team of IES & GATE Toppers

ECE SET-C

2013

ELECTRONICS & COMMN. ENGG. - EC

Let A be an $m \times n$ matrix and B an $n \times m$ matrix. It is given that determinant $(I_m + AB) =$ Q.35 determinant $(I_n + BA)$, where I_k is the $k \times k$ identity matrix. Using the above property, the determinant of the matrix given below is

$$\begin{bmatrix} 2 & 1 & 1 & 1 \\ 1 & 2 & 1 & 1 \\ 1 & 1 & 2 & 1 \\ 1 & 1 & 1 & 2 \end{bmatrix}$$

- (A) 2
- (B) 5
- (C) 8
- (D) 16

Let U and V be two independent zero mean Gaussian random variables of variances Q.36 respectively. The probability $P(3V \ge 2U)$ is

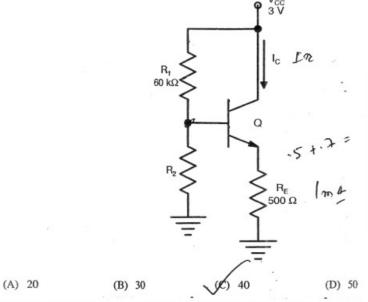
- (A) 4/9
- (B) 1/2
- (C) 2/3
- (D) 5/9

Q.37 Let U and V be two independent and identically distributed random variables such that $P(U=+1)=P(U=-1)=\frac{1}{2}$. The entropy H(U+V) in bits is

(A) 3/4

- (C) 3/2
- (D) log₂3

0.38 In the circuit shown below, the silicon npn transistor Q has a very high value of β . The required value of R_2 in $k\Omega$ to produce $I_C = 1$ mA is



EC-C



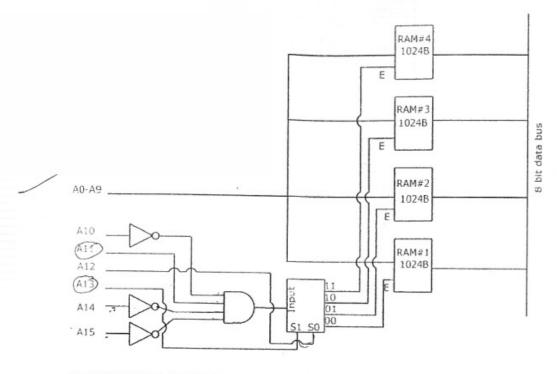
ECE SET-C

2013

2013

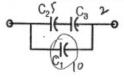
ELECTRONICS & COMMN. ENGG. - EC

There are four chips each of 1024 bytes connected to a 16 bit address bus as shown in the figure Q.39 below. RAMs 1, 2, 3 and 4 respectively are mapped to addresses



(A) 0C00H-0FFFH, 1C00H-1FFFH, 2C00H-2FFFH, 3C00H-3FFFH (B) 1800H-1FFFH, 2800H-2FFFH, 3800H-3FFFH, 4800H-4FFFH (C) 0500H-08FFH, 1500H-18FFH, 3500H-38FFH, 5500H-58FFH (D) 0800H-0BFFH, 1800H-1BFFH, 2800H-2BFFH, 3800H-3BFFH

Three capacitors C_1 , C_2 and C_3 whose values are $10\mu F$, $5\mu F$, and $2\mu F$ respectively, have breakdown Q.40 voltages of 10V, 5V, and 2V respectively. For the interconnection shown below, the maximum safe voltage in Volts that can be applied across the combination, and the corresponding total charge in µC stored in the effective capacitance across the terminals are respectively,



(A) 2.8 and 36

(B) 7 and 119

(C) 2.8 and 32

(D) 7 and 80

FC-C



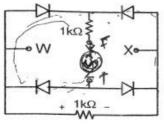
ECE SET-C

2013

2013

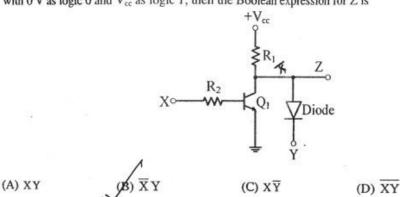
ELECTRONICS & COMMN. ENGG. - EC

Q.41 A voltage 1000 sin \(\omega\) t Volts is applied across YZ. Assuming ideal diodes, the voltage measured across WX in Volts, is

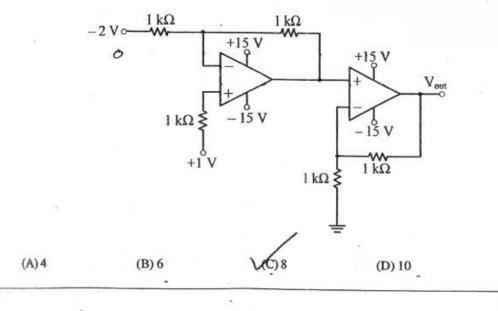


- (A) $\sin \omega t$
- (C) $(\sin \omega t |\sin \omega t|)/2$
- (B) $(\sin \omega t + |\sin \omega t|)/2$
- (b) 0 for all t

Q.42 In the circuit shown below, Q₁ has negligible collector-to-emitter saturation voltage and the diode drops negligible voltage across it under forward bias. If V_{cc} is +5 V, X and Y are digital signals with 0 V as logic 0 and V_{cc} as logic 1, then the Boolean expression for Z is



Q.43 In the circuit shown below the op-amps are ideal. Then Vout in Volts is



EC-C



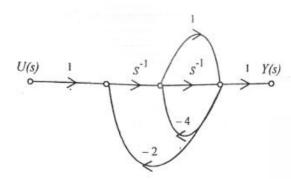
ECE SET-C

2013

2013

ELECTRONICS & COMMN. ENGG. - EC

Q.44 The signal flow graph for a system is given below. The transfer function $\frac{Y(s)}{U(s)}$ for this system is



(A)
$$\frac{s+1}{5s^2+6s+2}$$

$$(B) \frac{s+1}{s^2+6s+2}$$

(D)
$$\frac{1}{5s^2 + 6s + 2}$$

Q.45 The DFT of a vector $\begin{bmatrix} a & b & c & d \end{bmatrix}$ is the vector $\begin{bmatrix} \alpha & \beta & \gamma & \delta \end{bmatrix}$. Consider the product

$$[p \ q \ r \ s] = [a \ b \ c \ d] \begin{bmatrix} a \ b \ c \ d \\ d \ a \ b \ c \\ c \ d \ a \ b \\ b \ c \ d \ a \end{bmatrix}.$$

The DFT of the vector $[p \ q \ r \ s]$ is a scaled version of

(A)
$$\begin{bmatrix} \alpha^2 & \beta^2 & \gamma^2 & \delta^2 \end{bmatrix}$$

(B)
$$\left[\sqrt{\alpha} \quad \sqrt{\beta} \quad \sqrt{\gamma} \quad \sqrt{\delta} \right]$$

(C)
$$\left[\alpha + \beta \quad \beta + \delta \quad \delta + \gamma \quad \gamma + \alpha\right]$$

(D)
$$[\alpha \ \beta \ \gamma \ \delta]$$

Q.46 Consider two identically distributed zero-mean random variables U and V. Let the cumulative distribution functions of U and 2V be F(x) and G(x) respectively. Then, for all values of x

$$(\mathsf{A})\,F(x)-G(x)\leq 0$$

$$(B)F(x)-G(x)\geq 0 \quad \checkmark$$

$$(C)(F(x)-G(x))\cdot x\leq 0$$

$$(D)(F(x)-G(x))\cdot x\geq 0$$

- Q.47 A system described by a linear, constant coefficient, ordinary, first order differential equation has an exact solution given by $\dot{y}(t)$ for t > 0, when the forcing function is x(t) and the initial condition is y(0). If one wishes to modify the system so that the solution becomes -2y(t) for t > 0, we need to
 - (A) change the initial condition to -y(0) and the forcing function to 2x(t)
 - (B) change the initial condition to 2y(0) and the forcing function to -x(t)
 - (C) change the initial condition to $j\sqrt{2}y(0)$ and the forcing function to $j\sqrt{2}x(t)$
 - (D) change the initial condition to -2y(0) and the forcing function to -2x(t)

EC-C

-



ECE SET-C

2013

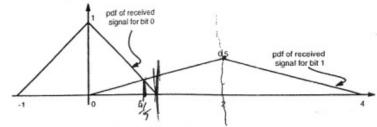
2013

ELECTRONICS & COMMN. ENGG. - EC

Common Data Questions

Common Data for Questions 48 and 49:

Bits 1 and 0 are transmitted with equal probability. At the receiver, the pdf of the respective received signals for both bits are as shown below.



Q.48 The optimum threshold to achieve minimum bit error rate (BER) is

(A)
$$\frac{1}{2}$$

$$\mathcal{J}(5) = \frac{4}{5}$$

(D)
$$\frac{3}{2}$$

Q.49 If the detection threshold is 1, the BER will be

(A)
$$\frac{1}{2}$$

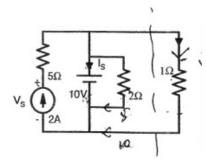
(B)
$$\frac{1}{4}$$

(C)
$$\frac{1}{8}$$

(D)
$$\frac{1}{16}$$

Common Data for Questions 50 and 51:

Consider the following figure



Q.50 The current in the 1Ω resistor in Amps is

(A)2

(B) 3.33



(D) 12

Q.51 The current I_S in Amps in the voltage source, and voltage V_S in Volts across the current source respectively, are

(A) 13, -20

(B) 8, -10

(C) - 8, 20





ECE SET-C

2013

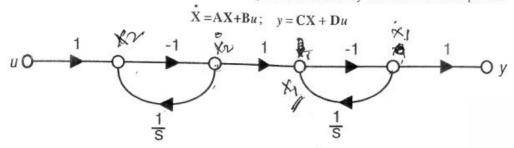
2013

ELECTRONICS & COMMN. ENGG. - EC

Linked Answer Questions

Statement for Linked Answer Questions 52 and 53:

The state diagram of a system is shown below. A system is described by the state-variable equations



The state-variable equations of the system shown in the figure above are 0.52

(A)
$$\dot{\mathbf{X}} = \begin{bmatrix} -1 & 0 \\ 1 & -1 \end{bmatrix} \mathbf{X} + \begin{bmatrix} -1 \\ 1 \end{bmatrix} u$$
$$y = \begin{bmatrix} 1 & -1 \end{bmatrix} \mathbf{X} + u$$

(B)
$$\dot{\mathbf{X}} = \begin{bmatrix} -1 & 0 \\ -1 & -1 \end{bmatrix} \mathbf{X} + \begin{bmatrix} -1 \\ 1 \end{bmatrix} u$$
$$y = \begin{bmatrix} -1 & -1 \end{bmatrix} \mathbf{X} + u$$

(C)
$$\dot{\mathbf{X}} = \begin{bmatrix} -1 & 0 \\ -1 & -1 \end{bmatrix} \mathbf{X} + \begin{bmatrix} -1 \\ 1 \end{bmatrix} u$$
$$y = \begin{bmatrix} -1 & -1 \end{bmatrix} \mathbf{X} - u$$

(D)
$$\dot{\mathbf{X}} = \begin{bmatrix} -1 & -1 \\ 0 & -1 \end{bmatrix} \mathbf{X} + \begin{bmatrix} -1 \\ 1 \end{bmatrix} u$$
$$y = \begin{bmatrix} 1 & -1 \end{bmatrix} \mathbf{X} - u$$

The state transition matrix e^{Ar} of the system shown in the figure above is

(A)
$$\begin{bmatrix} e^{-t} & 0 \\ te^{-t} & e^{-t} \end{bmatrix}$$

(B)
$$\begin{bmatrix} e^{-t} & 0 \\ -te^{-t} & e^{-t} \end{bmatrix}$$

(C)
$$\begin{bmatrix} e^{-t} & 0 \\ e^{-t} & e^{-t} \end{bmatrix}$$

$$(A) \begin{bmatrix} e^{-t} & 0 \\ te^{-t} & e^{-t} \end{bmatrix} \qquad (B) \begin{bmatrix} e^{-t} & 0 \\ -te^{-t} & e^{-t} \end{bmatrix} \qquad (C) \begin{bmatrix} e^{-t} & 0 \\ e^{-t} & e^{-t} \end{bmatrix} \qquad (D) \begin{bmatrix} e^{-t} & -te^{-t} \\ 0 & e^{-t} \end{bmatrix}$$



ECE SET-C

2013

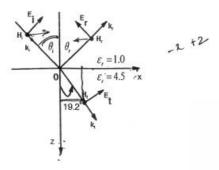
Ei

2013

ELECTRONICS & COMMN. ENGG. - EC

Statement for Linked Answer Questions 54 and 55:

A monochromatic plane wave of wavelength $\lambda = 600 \mu m$ is propagating in the direction as shown in the figure below. \vec{E}_i , \vec{E}_r , and \vec{E}_t denote incident, reflected, and transmitted electric field vectors associated with the wave.



Q.54 The angle of incidence θ_i and the expression for \vec{E}_i are

(A)
$$60^{\circ}$$
 and $\frac{E_0}{\sqrt{2}}(\hat{a}_x - \hat{a}_z)e^{-j\frac{\pi \times 10^{\circ}(x+\zeta)}{3\sqrt{2}}}$ V/m

(B) 45° and
$$\frac{E_0}{\sqrt{2}} (\hat{a}_x + \hat{a}_z) e^{-j\frac{\pi \times 40^4 z}{3}} \text{V/m}$$

(C) 45° and $\frac{E_0}{\sqrt{2}} (\hat{a}_x - \hat{a}_z) e^{-j\frac{\pi \times 40^4 (x+z)}{3\sqrt{2}}} \text{V/m}$

(D) 60° and
$$\frac{E_0}{\sqrt{2}}(\hat{a}_x - \hat{a}_z)e^{-j\frac{\pi \times 10^4 z}{3}}$$
V/m

Q.55 The expression for \vec{E}_r is

(A)
$$0.23 \frac{E_0}{\sqrt{2}} (\hat{a}_x + \hat{a}_z) e^{-j\frac{x \times 10^4 (x-z)}{3\sqrt{2}}} \text{V/m}$$

(B)
$$-\frac{E_0}{\sqrt{2}} (\hat{a}_x + \hat{a}_z) e^{j\frac{\pi \times 10^4 z}{3}} \text{V/m}$$

$$\sqrt{(2)} 0.44 \frac{E_0}{\sqrt{2}} (\hat{a}_x + \hat{a}_z) e^{-j\frac{\pi \times 10^4 (x-z)}{3\sqrt{2}}} \text{V/m}$$

(D)
$$\frac{E_0}{\sqrt{2}} (\hat{a}_x + \hat{a}_z) e^{-j\frac{\pi \times 10^4 (x+z)}{3}} \text{V/m}$$



ECE SET-C

0.56	to Q.60 carry o	ne mark each				
Q.50	Complete the sen					
	19-12-19-20-20-20-20-20-20-20-20-20-20-20-20-20-	mistakes. to commit				
	(A) commit		(C) committed	(D) committing		
Q.57		sted not to quarrel with				
	Which one of the	following options is th	e closest in meaning to the	word quarrel?		
	(A) make out	(B) call out	dig out	(D) fall out		
Q.58	Statement: You	can always give me a ri	ng whenever you need.			
- 10			ference from the above sta	itement?		
6	(A) Because I hav (B) Because I hav	ve a nice caller tune. ve a better telephone fac end in need is a friend in	cility.	;		
	(D) Because you	need not pay towards th	ndeed. De telephone hills when vo	u give me a ring		
(D) Because you need not pay towards the telephone bills when you give me a ring. Q.59 In the summer of 2012, in New Delhi, the mean temperature of Monday to Wednesday was 41°C and of Tuesday to Thursday was 43°C. If the temperature on Thursday was 15% higher than that of Monday, then the temperature in °C on Thursday was						
	(A) 40 ·	(B) 43	6)46	(D) 49		
Q.60	Choose the gram	matically CORRECT s	V	0 i		
43	(A) Two and two (B) Two and two (C) Two and two (D) Two and two	add four. become four. are four.	enerce.			
0.61	to Q.65 carry tv					
		12	102000 to saturation of			
Q.61			of the equation $3x^2+2x+p$	(p-1) = 0 are of opposite s		
	(A) (-∞, 0)	(P) (0, 1)	(C) (1, ∞)	(D) (0, ∞)	- tcr	
Q.62	What is the chance	e that a leap year, selec	ted at random, will contain	53 Saturdays?		
	JA)211	(B) 3/7	(C) 1/7	(D) 5/7		
Q.63	Find the sum to n	terms of the series 10+	8A± 73A±			
	(A) $\frac{9(9^{n}+1)}{10}+1$ (B) $\frac{9(9^{n}-1)}{8}+1$ (C) $\frac{9(9^{n}-1)}{8}+n$ (D) $\frac{9(9^{n}-1)}{8}+n$	le:				
	(D) $\frac{9(9^n-1)}{8^n} + n$	2	,	-		
c-c					17/24	

2013



2013 A Team of IES & GATE Toppers ECE SET-C

2013

ELECTRONICS & COMMN. ENGG. - EC

Q.64 Statement: There were different streams of freedom movements in colonial India carried out by the moderates, liberals, radicals, socialists, and so on.

Which one of the following is the best inference from the above statement?

- (A) The emergence of nationalism in colonial India led to our Independence.
- (B) Nationalism in India emerged in the context of colonialism.
- (C) Nationalism in India is homogeneous.
- Nationalism in India is heterogeneous.
- Q.65 A car travels 8 km in the first quarter of an hour, 6 km in the second quarter and 16 km in the third quarter. The average speed of the car in km per hour over the entire journey is

(A) 30

(B) 36

(2) 40

(D) 24

END OF THE QUESTION PAPER